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Bib Data Sheet

CONFIRMATION NO. 2035

SERIAL NUMBER 10/693,803	FILING DATE 10/24/2003  RULE	CLASS 257	GROUP ART UNIT 2826	ATTORNEY DOCKET NO. 132852-1 GCRZ 200025
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\*\* CONTINUING DATA \*\*\*\*\* NB HT

\*\* FOREIGN APPLICATIONS \*\*\*\*\* no HT

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 01/26/2004

Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	STATE OR COUNTRY NY	SHEETS DRAWING 14	TOTAL CLAIMS 49	INDEPENDENT CLAIMS 5
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
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## TITLE

Group III-nitride based resonant cavity light emitting devices fabricated on single crystal gallium nitride substrates

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
		<input type="checkbox"/> 1.17 Fees ( Processing Ext. of